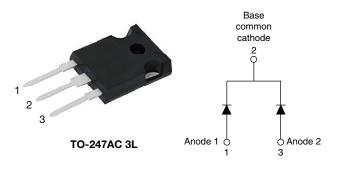
**Vishay Semiconductors** 

Ultrafast Rectifier, FRED Pt<sup>®</sup>, 2 x 30 A



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PRIMARY CHARACTERISTICS										
I <sub>F(AV)</sub>	2 x 30 A									
V <sub>R</sub>	600 V									
V <sub>F</sub> at I <sub>F</sub>	1.1 V									
t <sub>rr</sub> typ.	27 ns									
T <sub>J</sub> max.	175 °C									
Package	TO-247AC 3L									
Circuit configuration	Common cathode									

### **FEATURES**

- · Ultrafast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature



- · Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

VS-60CPU06... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, welding, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage		V <sub>RRM</sub>		600	V				
Average rectified forward current	per leg	I <sub>F(AV)</sub>		30					
	per device		Rated V <sub>R</sub> , T <sub>C</sub> = 137 °C	60	٨				
Non-repetitive peak surge current per leg		I <sub>FSM</sub>	T <sub>J</sub> = 25 °C, t <sub>p</sub> = 10 ms	300	A				
Peak repetitive forward current per leg		I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 137 °C	60					
Operating junction and storage ten	nperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C				

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)										
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS					UNITS				
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA		-	-					
Econyard voltage	VF	I <sub>F</sub> = 30 A	-	1.31	1.65	V				
Forward voltage	٧F	I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.1	1.4					
Deverae leekeese eurrent		$V_R = V_R$ rated	-	0.02	50					
Reverse leakage current	I <sub>R</sub>	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	30	250	μA				
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	22	-	pF				
Series inductance	Ls	Measured lead to lead 5 mm from package body	-	3.5	-	nH				

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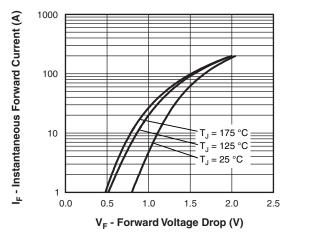
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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)											
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS				
		$I_F = 1.0 \text{ A}, \ dI_F/dt = 10$	0 A/µs, V <sub>R</sub> = 30 V	-	27	35					
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	42	-	ns A nC				
		T <sub>J</sub> = 125 °C		-	110	-					
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	l <sub>F</sub> = 30 A dI <sub>F</sub> /dt = - 200 A/μs	-	5	-					
		T <sub>J</sub> = 125 °C	$V_{\rm R} = 200  \text{V}$	-	11	-					
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	110	-					
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	630	-	nc				

THERMAL - MECHANICAL SPECIFICATIONS (T <sub>J</sub> = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C				
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	0.6	0.9					
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W				
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.4	-					
Weight			-	6.0	-	g				
weight			-	0.22	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style TO-247AC 3L		60CI	PU06					

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Fig. 1 - Typical Forward Voltage Drop Characteristics

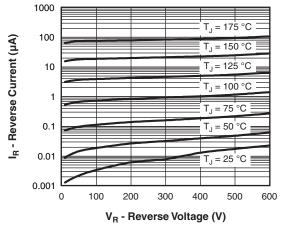


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

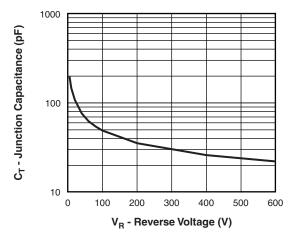


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

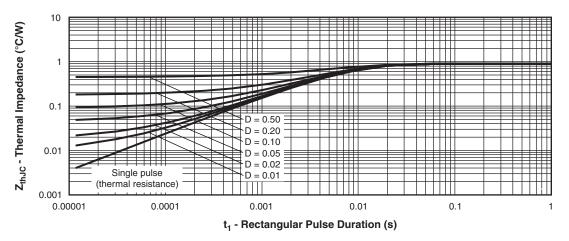
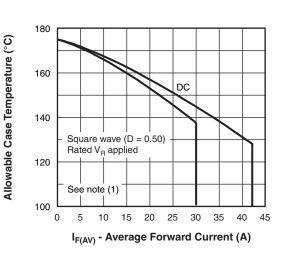


Fig. 4 - Maximum Thermal Impedance  $Z_{\text{thJC}}$  Characteristics

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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

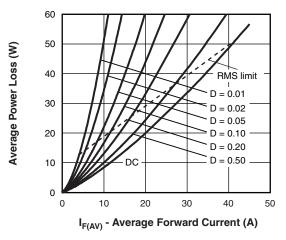


Fig. 6 - Forward Power Loss Characteristics

#### Note

 $^{(1)}$  Formula used:  $T_{C} = T_{J} - (Pd + Pd_{REV}) \times R_{th,JC};$ Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6); Pd\_{REV} = inverse power loss =  $V_{R1} \times I_{R}$  (1 - D);  $I_{R}$  at  $V_{R1}$  = rated  $V_{R}$ 

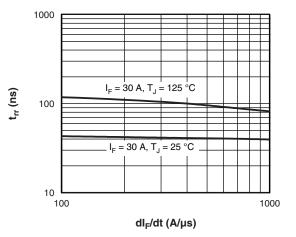


Fig. 7 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

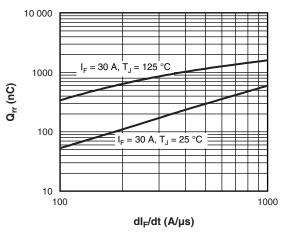


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

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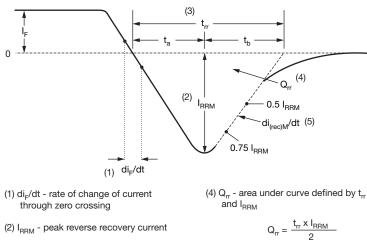
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(3) t<sub>rr</sub> - reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75  $\mathrm{I}_{\mathrm{RRM}}$  and 0.50  $\mathrm{I}_{\mathrm{RRM}}$ extrapolated to zero current.

(2)  $I_{\text{RRM}}$  - peak reverse recovery current

(5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 9 - Reverse Recovery Waveform and Definitions

### **ORDERING INFORMATION TABLE**

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Device code	VS-	60	С	Р	U	06	-N3
		2	3	4	5	6	7
	1 - 2 - 3 -	Cur	rent rati	niconduo ng (60 = iguratior	60 A)	oduct	
	4 -	Pac	kage:	n catho			
	5 - 6 - 7 -	U = Voli	ultrafas age rati	t rectifie ng (06 = ntal digit	r = 600 V)	1	
		-N3	= halog	gen-free	, RoHS-	complia	ant, and

ORDERING INFORMATION (Example)									
PREFERRED P/N	PACKAGING DESCRIPTION								
VS-60CPU06-N3	25	500	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?96138							
Part marking information	www.vishay.com/doc?95007							
SPICE model	www.vishay.com/doc?96084							

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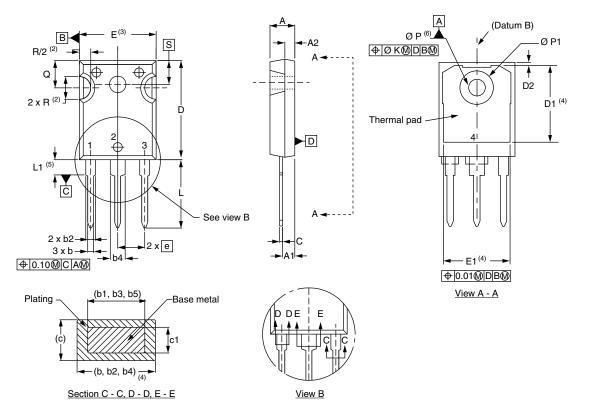


# **Outline Dimensions**

**Vishay Semiconductors** 

# **TO-247AC 3L**

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0	)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØΡ	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3	]	S	5.51	BSC	0.217	' BSC	
D1	13.08	-	0.515	-	4							

Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(4)</sup> Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension Q

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